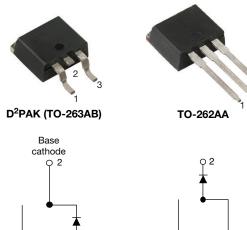


### **Vishay Semiconductors**

# Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup>

2



3 **Ċ1** 

VS-ETH1506S-M3

N/C

3

Anode

N/C Anode VS-ETH1506-1-M3

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	15 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.25 V							
t <sub>rr</sub> (typ.)	21 ns							
T <sub>J</sub> max.	175 °C							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Single							

#### **FEATURES**

- · Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- RoHS COMPLIANT HALOGEN FREE

AUTOMOTIVE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 139 °C	15	^						
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	160	A						
Operating junction and storage temperatures	TJ, T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	v				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15A	-	1.8	2.45	v				
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.25	1.6					
Povorao lookogo ourropt		$V_{R} = V_{R}$ rated	-	0.01	15					
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \ ^{\circ}C, V_R = V_R \ rated$ - 20		20	200	μA				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

Revision: 01-Aug-2023

Document Number: 94482



www.vishay.com

## Vishay Semiconductors

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CC	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	100 A/µs, V <sub>R</sub> = 30 V	-	21	26				
Reverse recovery time	+	I <sub>F</sub> = 1.5 A, dI <sub>F</sub> /dt =	100 A/µs, V <sub>R</sub> = 30 V	-	25	36	200			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	29	-	ns			
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dl <sub>F</sub> /dt = 200 A/µs	-	65	-				
Deals receivers aurrent		T <sub>J</sub> = 25 °C		-	3.9	-	A			
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	7.0	-				
Reverse recovery charge	0	T <sub>J</sub> = 25 °C	VR - 050 V	-	60	-				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	240	-	no			
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 15 A	-	42	-	ns			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$dI_F/dt = 800 \text{ A/}\mu\text{s}$	-	21	-	А			
Reverse recovery charge	Q <sub>rr</sub>	]	V <sub>R</sub> = 390 V	-	480	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	1.3	1.51	°C/W				
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70					
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-					
Weight			-	2.0	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)				
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)		ETH1	506SH					
Marking device		Case style TO-262AA		ETH1506-1H						

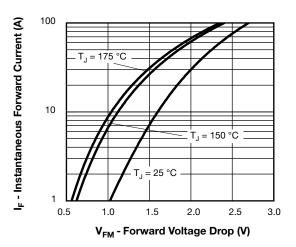


Fig. 1 - Typical Forward Voltage Drop Characteristics

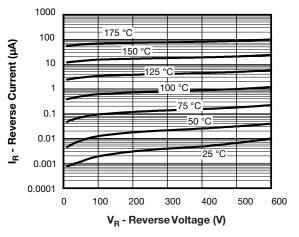


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Revision: 0	1-Aug-2023
-------------	------------

2

Document Number: 94482

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



**Vishay Semiconductors** 

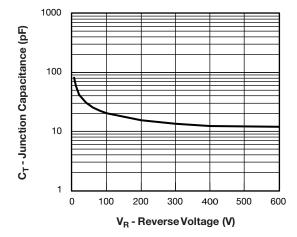


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

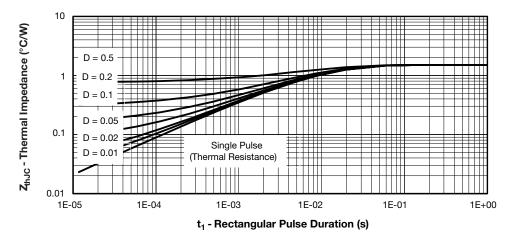


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

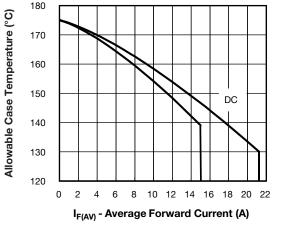


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

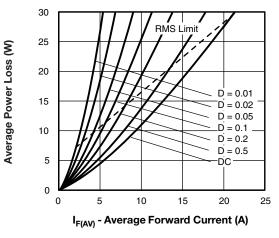


Fig. 6 - Forward Power Loss Characteristics

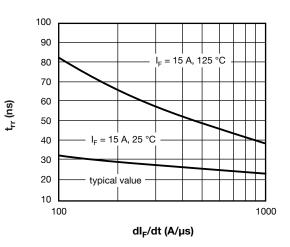
Revision: 01-Aug-2023

3

Document Number: 94482

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

SHA

Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

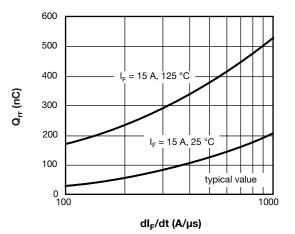


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

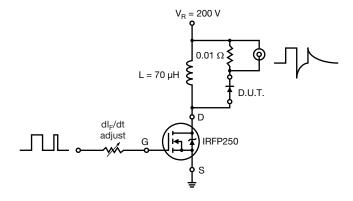
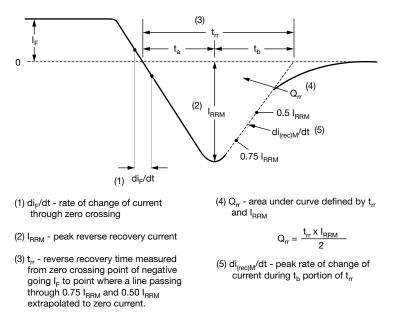
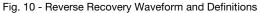
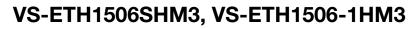


Fig. 9 - Reverse Recovery Parameter Test Circuit







VISHA www.vishay.com

## Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code	VS-	E	т	н	15	06	S	TRL	н	М3	
	1	2	3	4	5	6	7	8	9	(10)	
	1 - Vishay Semiconductors product										
	2	<ul> <li>2 - Circuit configuration</li> <li>E = single diode</li> </ul>									
	3										
	4	- H=	H = Hyperfast recovery time								
	5	- Cur	Current code (15 = 15 A)								
	6	- Volt	tage coo	le (06 =	600 V)						
	7	- •S	= D <sup>2</sup> PAI	K							
		- •-1	= TO-2	62							
	8	- • No	one = tu	be							
		- • TF	<ul> <li>TRL = tape and reel (left oriented, for D<sup>2</sup>PAK package)</li> </ul>								
		- • TF	• TRR = tape and reel (right oriented, for $D^2PAK$ package)								
	9	- н=	H = AEC-Q101 qualified								
	10	- Env	vironmer = halog	ntal digit	:	complia	nt, and	termina	itions lea	ad (Pb)-	

ORDERING INFORMATION (Example)									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-ETH1506SHM3	50	Antistatic plastic tube							
VS-ETH1506-1HM3	50	Antistatic plastic tube							
VS-ETH1506STRRHM3	800	13" diameter reel							
VS-ETH1506STRLHM3	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS								
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95046						
Dimensions	TO-262AA	www.vishay.com/doc?95419						
Port marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444						
Part marking information	TO-262AA	www.vishay.com/doc?95443						
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95032						

# **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

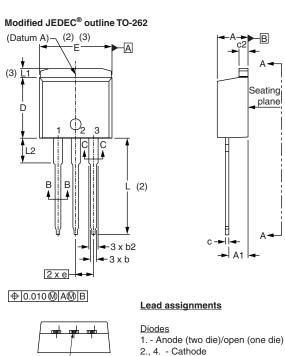
## **Outline Dimensions**



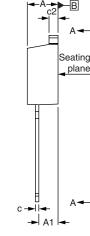
**Vishay Semiconductors** 

**TO-262** 

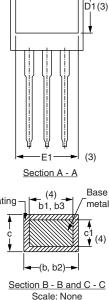
#### **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 \_ 1.65 0.065 3 \_ 3.36 0.132 0.146 L2 3.71

3. - Anode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1